

# SCS206AG

SiC Schottky Barrier Diode

V <sub>R</sub>	650V
I <sub>F</sub>	6A
Q <sub>C</sub>	9nC

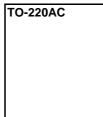
#### Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

#### Applications

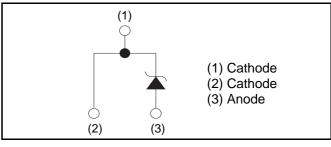
- PFC Boost Topology
- Secondary Side Rectification
- Data Center
- PV Power Conditioners

### ●Outline



# 

#### Inner circuit



#### Packaging specifications

	Packaging	Tube
	Reel size (mm)	-
Tuno	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	С
	Marking	SCS206AG

#### •Absolute maximum ratings $(T_j = 25^{\circ}C)$

	<b>U</b>			
Parameter		Symbol	Value	Unit
Reverse voltage (re	petitive peak)	V <sub>RM</sub>	650	V
Reverse voltage (D	C)	V <sub>R</sub>	650	V
Continuous forward	current $(T_c= 138^{\circ}C)$	I <sub>F</sub>	6	А
Surge non-	PW=10ms sinusoidal, T <sub>j</sub> =25°C		23	А
repetitive forward current	PW=10ms sinusoidal, T <sub>j</sub> =150°C	I <sub>FSM</sub>	18	А
	PW=10µs square, T <sub>j</sub> =25°C		90	А
Repetitive peak forward current		I <sub>FRM</sub>	27 <sup>*1</sup>	А
i <sup>2</sup> t value	PW=10ms, T <sub>j</sub> =25°C	<b>f</b> 12 11	2.6	A <sup>2</sup> s
I t value	PW=10ms, T <sub>j</sub> =150°C	∫ i²dt	1.6	A <sup>2</sup> s
Total power dissipation		P <sub>D</sub>	51 <sup>*2</sup>	W
Junction temperature		Tj	175	°C
Range of storage temperature		T <sub>stg</sub>	-55 to +175	°C
*4 T 100°C T	450% Duty avala $40%$ *0 T 0			

\*1  $T_c=100^{\circ}C$ ,  $T_j=150^{\circ}C$ , Duty cycle=10% \*2  $T_c=25^{\circ}C$ 

## •Electrical characteristics ( $T_j = 25^{\circ}C$ )

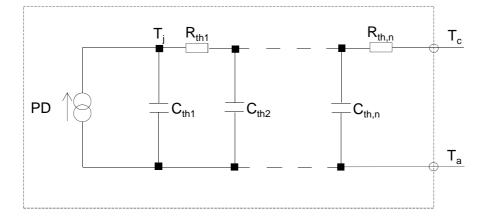
Deremeter	Symbol	Conditions	Values			Unit
Parameter	Symbol Conditions		Min.	Тур.	Max.	Unit
DC blocking voltage	V <sub>DC</sub>	I <sub>R</sub> =1.2mA	650	-	-	V
		I <sub>F</sub> =6A,T <sub>j</sub> =25°C	-	1.35	1.55	V
Forward voltage	V <sub>F</sub>	I <sub>F</sub> =6A,T <sub>j</sub> =150°C	-	1.55	-	V
	I <sub>F</sub> =6A,T <sub>j</sub> =175°C	-	1.63	-	V	
	I <sub>R</sub>	V <sub>R</sub> =600V,T <sub>j</sub> =25°C	-	1.2	120	μA
Reverse current		V <sub>R</sub> =600V,T <sub>j</sub> =150°C	-	18	-	μA
		V <sub>R</sub> =600V,T <sub>j</sub> =175°C	-	42	-	μA
Total conscitance	С —	V <sub>R</sub> =1V,f=1MHz	-	220	-	pF
Total capacitance		V <sub>R</sub> =600V,f=1MHz	-	22	-	pF
Total capacitive charge	Q <sub>C</sub>	V <sub>R</sub> =400V,di/dt=350A/µs	-	9	-	nC
Switching time	t <sub>C</sub>	V <sub>R</sub> =400V,di/dt=350A/μs	-	12	-	ns

#### •Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
	Symbol		Min.	Тур.	Max.	Unit
Thermal resistance	R <sub>th(j-c)</sub>	-	-	2.6	2.9	°C/W

#### •Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R <sub>th1</sub>	1.00E+00		C <sub>th1</sub>	1.13E-03	
R <sub>th2</sub>	1.28E+00	K/W	C <sub>th2</sub>	3.44E-03	Ws/K
R <sub>th3</sub>	2.70E-01		C <sub>th3</sub>	3.11E-01	



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#### •Electrical characteristic curves



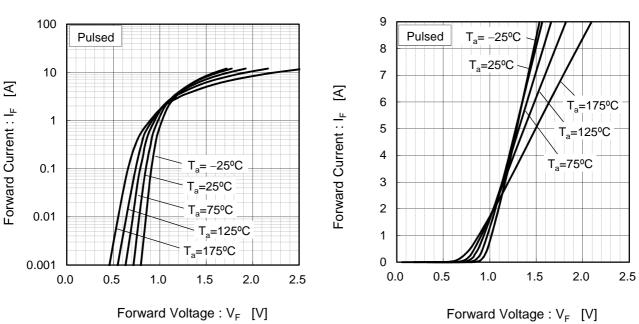


Fig.3  $V_R$  -  $I_R$  Characteristics

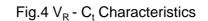
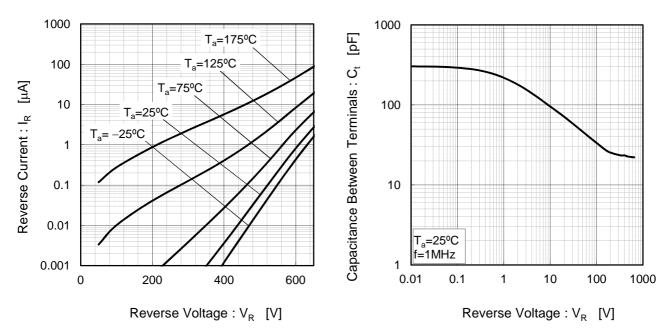
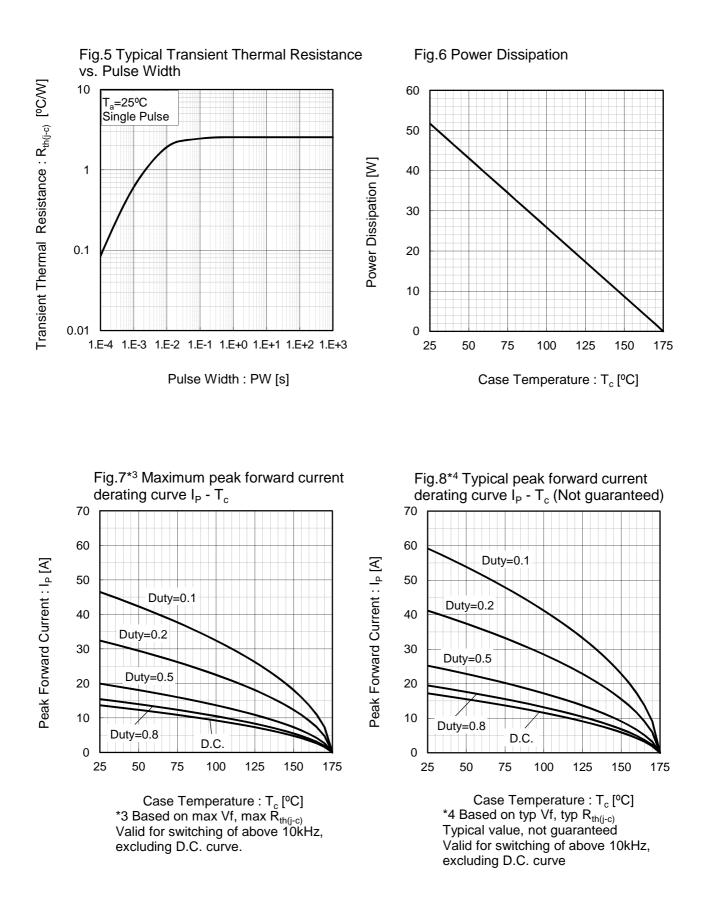


Fig.2  $V_F$  -  $I_F$  Characteristics



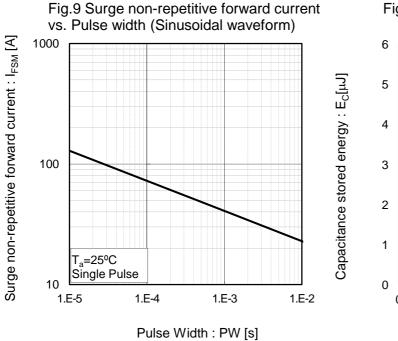


#### •Electrical characteristic curves

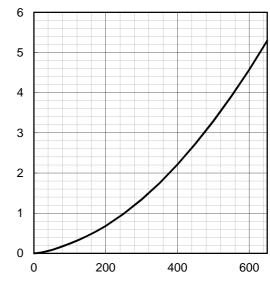




#### •Electrical characteristic curves



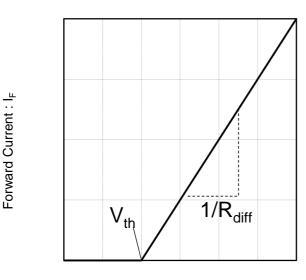
#### Fig.10 Typical capacitance store energy



Reverse Voltage :  $V_R$  [V]

#### •Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage :  $V_F$ 

 $V_F = V_{th} + R_{diff} I_F$ 

V <sub>th</sub> (T <sub>j</sub>	$) = a_0 + a_1^{-1}$	T <sub>j</sub>
$R_{diff} (T_j)$	$) = b_0 + b_1$	$T_{j} + b_{2} T_{j}^{2}$

Symbol	Typical Value	Unit
a <sub>0</sub>	9.35E-01	V
a <sub>1</sub>	-1.12E-03	V/°C
b <sub>0</sub>	6.63E-02	Ω
b <sub>1</sub>	1.70E-04	Ω/°C
b <sub>2</sub>	1.80E-06	$\Omega/^{\circ}C^{2}$

 $T_i \text{ in } {}^\circ\text{C}; -55 \, {}^\circ\text{C} < T_i < {}^\circ\text{C}; I_F < 12 \text{ A}$ 



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